TOSHIBA PHOTOCOUPLER IRED & PHOTO-IC

TLP116A

Plasma Display Panels (PDPs) High-Speed Interface Factory Automation (FA)

The Toshiba TLP116A mini-flat coupler is a small-outline coupler suitable for surface-mount assembly. The TLP116A consists of an infrared LED and an integrated high-gain, high-speed photodetector. This unit is housed in the 6-pin SO package and guarantees a creepage distance of \geq 5.0mm, a clearance of \geq 5.0mm and an insulation thickness of \geq 0.4mm. Therefore, the TLP116A meets the reinforced insulation class requirements of international safety standards.

- Inverter logic (totem-pole output)
- SO6 package
- Guaranteed performance over: −40 to 100°C
- Power supply voltage: 4.5 to 5.5V
- Input thresholds current: I_{FHL} = 5 mA (max)
- Propagation delay time (tpHL / tpLH): 60 ns (max)
- Switching speed: 20 MBd (typ.)
- Common-mode transient immunity: 10 kV/μs
- Isolation voltage: 3750 Vrms
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A

File No.E67349

CQC-approved: GB4943.1,GB8898 Japan and Thailand Factory



VDE-approved: EN 60747-5-5, EN 62368-1 (Note 1)

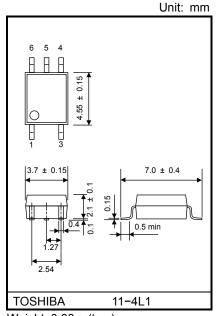
Note 1: When a VDE approved type is needed, please designate the **Option(V4)**.

Truth Table

Input	LED	Tr1	Tr2	Output
Н	ON	OFF	ON	L
L	OFF	ON	OFF	Н

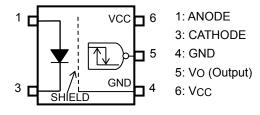
Construction Mechanical Rating

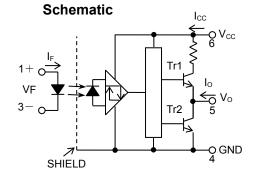
Creepage Distance: 5.0mm (min)
Clearance: 5.0mm (min)
Insulation Thickness: 0.4mm (min)



Weight: 0.08 g (typ.)

Pin Configuration (Top View)





A bypass capacitor of $0.1\mu F$ must be connected between pins 6 and 4.

Start of commercial production 2008-07

Absolute Maximum Ratings (Ta=25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	lF	20	mA
	Forward current derating (Ta ≥ 85°C)	ΔI _F / °C	-0.5	mA/°C
ED	Peak transient forward current (Note 1)	IFPT	1	Α
"	Reverse voltage	V _R	5	V
	Input power dissipation	PD	40	mW
	Input power dissipation derating (Ta ≥ 85°C)	ΔPD/°C	-1.0	mW/°C
	Output current	lo	10	mA
DETECTOR	Output current derating (Ta ≥ 85°C)		-0.25	mA/°C
EC.	Output voltage	VO	6	V
DEJ	Supply voltage	VCC	6	V
	Output power dissipation	PO	40	mW
Oper	ating temperature range	Topr	-40 to 100	°C
Stora	ge temperature range	Tstg	-55 to 125	°C
Lead	solder temperature(10 s)	Tsol	260	°C
Isola	tion voltage (AC,60 s, R.H. ≤ 60 %) (Note 2)	BVs	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1 : Pulse width PW \leq 1 μ s, 300 pps.

Note 2: This device is regarded as a two terminal device: pins 1 and 3 are shorted together, as are pins 4,5 and 6.

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Input current ON	I _F (ON)	8		18	mA
Input voltage , OFF	V _F (OFF)	0	_	0.8	V
Supply voltage	VCC	4.5	5.0	5.5	V
Operating temperature	Topr	-40		100	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note: The detector of this product requires a power supply voltage (VCC) of 4.5 V or higher for stable operation. If the VCC is lower than this value, an ICC may increase, or an output may be unstable.

Be sure to use the product after checking the supply current, and the operation of a power-on/-off.

Correlation between Input current, switching speed and drive circuit (reference information).

Input current (IF)	Test Circuit	Typical switching speed
12mA	1 (Page 4)	21 to 23 MBd
8mA	1 (Page 4)	18 to 20 MBd
8mA	2 (Page 4, With Speed up capacitor)	23 to 27 MBd

Downloaded from Arrow.com.



Electrical Characteristics

(Unless otherwise specified, Ta=-40 to 100°C, V_{CC}=4.5 to 5.5 V)

Characteristic	Symbol	Test Circuit	Conditions	Min	Тур.	Max	Unit
Input forward voltage	V _F	_	I _F = 10 mA ,Ta = 25 °C	1.45	1.58	1.85	٧
Temperature coefficient of forward voltage	ΔV _F /ΔTa	_	I _F = 10 mA	_	-2.0	_	mV/°C
Input reverse current	I_{R}	_	V _R =5 V, Ta = 25 °C	_	_	10	μΑ
Capacitance between Input terminals	C _T		V _F = 0 V, f= 1 MHz, Ta = 25 °C		60		pF
Logic low output voltage	V _{OL}	1	I _{OL} = 1.6 mA, I _F = 12 mA, V _{CC} = 5 V			0.4	٧
Logic high output voltage	Voн	2	$I_{OH} = -0.02 \text{ mA},$ V _F = 1.05 V, V _{CC} = 5 V	4.0			٧
Logic low supply current	^I CCL	3	I _F = 12 mA	_	_	5.0	mA
Logic high supply current	Іссн	4	V _F = 0 V			5.0	mA
Input current logic low output	IFHL		I _O = 1.6 mA, V _O < 0.4 V			5	mA
Input voltage logic high output	V _{FLH}	_	I _O = -0.02 mA, V _O > 4.0 V	0.8	_	_	٧

^{*}All typical values are at Ta=25°C, V_{CC} =5 V, $I_F(ON)$ =12 mA unless otherwise specified

Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Conditions	Min	Тур.	Max	Unit
Capacitance input to output	Cs	Vs = 0 V,f = 1 MHz	_	0.8	-	pF
Isolation resistance	Rs	R.H. ≤ 60 %, V _S = 500 V	10 ¹²	10 ¹⁴	_	Ω
Isolation voltage	BVs	AC, 60 s	3750	_	_	V _{rms}

Note: This device is regarded as a two terminal device: pins 1 and 3 are shorted together, as are pins 4,5 and 6.

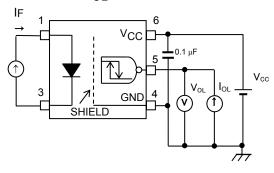
Switching Characteristics (Unless otherwise specified, Ta=-40 to 100°C, VCC=4.5 to 5.5 V)

Characteristic	Symbol	Test Circuit	Cond	ditions	Min	Тур.	Max	Unit
Propagation delay time to logic high output	tpHL	_	I _F = 0→12 mA	RIN = 100 Ω	_	ı	60	ns
Propagation delay time to logic low output	tpLH	5	I _F = 12→0 mA	$C_L = 15 \text{ pF}$ (Note 1)	_	l	60	ns
Propagation delay time to logic high output	tpHL	6	$V_{IN} = 0 \rightarrow 5 \text{ V}$ $(I_F = 0 \rightarrow 8 \text{ mA})$	R _{IN} = 470 Ω C _{IN} = 27 pF	_	ı	60	ns
Propagation delay time to logic low output	tpLH		$V_{IN} = 5 \rightarrow 0 \text{ V}$ $C_L = 15 \text{ pF}$ $(Note 1)$	C _L = 15 pF (Note 1)	_	l	60	ns
Switching time dispersion between ON and OFF	tpHL- tpLH		I _F = 12 mA , R _{IN} CL =15 pF (Note		_		30	ns
Output fall time(90-10%)	tf	5	I _F = 0→12 mA	R _{IN} = 100 Ω	_	15	_	ns
Output rise time(10-90%)	tr		I _F = 12→0 mA	C _L = 15 pF (Note 1)	_	15	_	ns
Common mode transient immunity at high Level output	СМН	7	V _{CM} = 1000 V _P - Vo(Min) = 4 V, Ta	*	10000			V/μs
Common mode transient immunity at low level output	CML	7	V _{CM} = 1000 Vp-p, I _F = 12 mA, Vo(Max) = 0.4 V, Ta = 25°C		-10000	_		V/μs

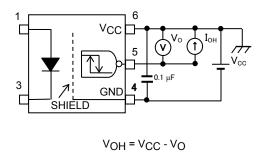
^{*}All typical values are at Ta=25°C

Note 1: C_L is less than 15 pF which includes probe and Jig/stray wiring capacitance.

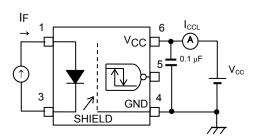
TEST CIRCUIT 1: VOL



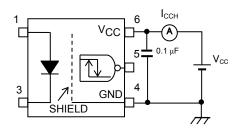
TEST CIRCUIT 2: VOH



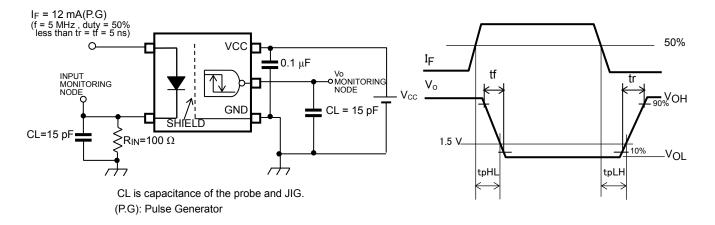
TEST CIRCUIT 3: ICCL



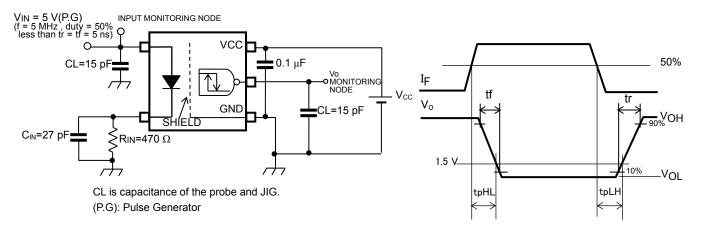
TEST CIRCUIT 4: ICCH



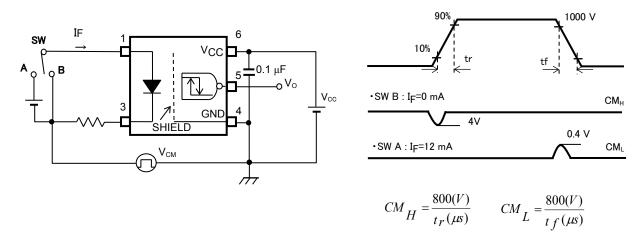
TEST CIRCUIT 5: tpHL, tpLH



TEST CIRCUIT 6: tpHL, tpLH



TEST CIRCUIT 7: Common-Mode Transient Immunity Test Circuit



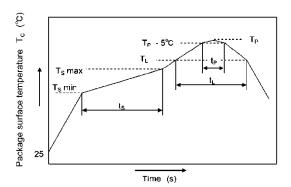
Soldering and Storage

1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

1) When Using Soldering Reflow

An example of a temperature profile when lead(Pb)-free solder is used.



	Symbol	Min	Max	Unit
Preheat temperature	Ts	150	200	°C
Preheat time	ts	60	120	s
Ramp-up rate (T _L to T _P)			3	°C/s
Liquidus temperature	TL	217		°C
Time above T _L	t∟	60	150	s
Peak temperature	Tp		260	ů
Time during which T_c is between ($T_P = 5$) and T_P	t _P		30	S
Ramp-down rate (T _P to T _L)			6	°C/s

- The soldering temperature profile is based on the package surface temperature (See the figure shown above.)
- Reflow soldering must be performed once or twice.
- The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

2) When using soldering Flow

- Preheat the device at a temperature of 150 °C (package surface temperature) for 60 to 120 seconds.
- Mounting condition of 260 °C within 10 seconds is recommended
- Flow soldering must be performed once.

3) When using soldering Iron

- Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C.
 - Heating by soldering iron must be done only once per lead.

2. Precautions for General Storage

- 1) Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- 2) Follow the precautions printed on the packing label of the device for transportation and storage.
- 3) Keep the storage location temperature and humidity within a range of 5°C to 35°C and 45% to 75%, respectively.
- 4) Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- 5) Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- 6) When restoring devices after removal from their packing, use anti-static containers.
- 7) Do not allow loads to be applied directly to devices while they are in storage.
- 8) If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE
 EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH
 MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT
 ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without
 limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical
 equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to
 control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant. IF YOU USE
 PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your
 TOSHIBA sales representative or contact us via our website.
- . Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
 FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY
 WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR
 LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND
 LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO
 SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS
 FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- GaAs (Gallium Arsenide) is used in Product. GaAs is harmful to humans if consumed or absorbed, whether in the form of dust or vapor. Handle with care and do not break, cut, crush, grind, dissolve chemically or otherwise expose GaAs in Product.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without
 limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile
 technology products (mass destruction weapons). Product and related software and technology may be controlled under the
 applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the
 U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited
 except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of
 Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled
 substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES
 OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

TOSHIBA ELECTRONIC DEVICES & STORAGE CORPORATION

https://toshiba.semicon-storage.com/